

COMPOUND TRANSISTOR

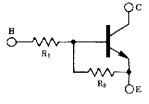
on-chip resistor NPN silicon epitaxial transistor For mid-speed switching

FEATURES

 On-chip bias resistor (R₁ = 4.7 kΩ, R₂ = 4.7 kΩ)

Complementary transistor with AN1L3M

ABSOLUTE MAXIMUM RATINGS (Ta = 25° C)

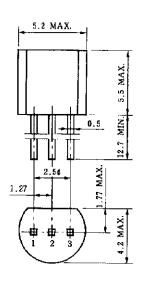


Symbol Unit Parameter Ratings v Collector to base voltage Vсво 60 Collector to emitter voltage v VCEO 50 Emitter to base voltage Vево 10 ٧ Collector current (DC) 100 C(DC) mΑ Collector current (Pulse) IC(pulse) * 200 mΑ Ρт 250 Total power dissipation mW °C Junction temperature Tj 150 °C -55 to +150 Storage temperature Tstg

* PW \leq 10 ms, duty cycle \leq 50 %

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

PACKAGE DRAWING (UNIT: mm)



Electrode Connection

1. Emitter EIAJ : SC-43B

2. Collector JEDEC: TO-92

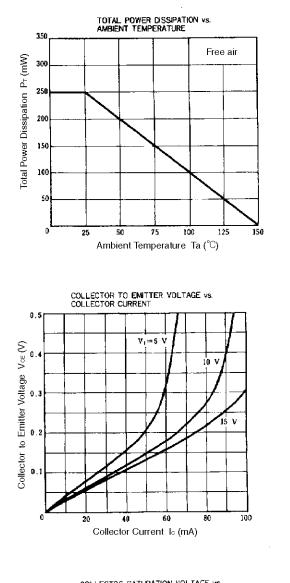
3. Base IF.C : PA33

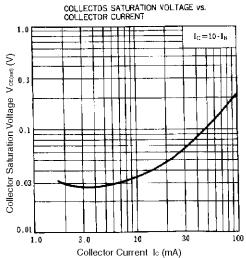
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = 50 V, IE = 0			100	nA
DC current gain	hfe1 **	Vce = 5.0 V, Ic = 5.0 mA	20	40	80	-
DC current gain	hfe2 **	Vce = 5.0 V, Ic = 50 mA	70	140		-
Collector saturation voltage	V _{CE(sat)} **	Ic = 5.0 mA, I _B = 0.25 mA		0.08	0.3	V
Low level input voltage	VIL **	$V_{CE} = 5.0 \text{ V}, \text{ Ic} = 100 \ \mu\text{A}$		1.1	0.8	V
High level input voltage	VIH **	Vce = 0.2 V, Ic = 5.0 mA	3.0	1.5		V
Input resistance	R1		3.28	4.7	6.11	kΩ
Resistance ratio	R1/R2		0.9	1.0	1.1	-
Turn-on time	ton	$V_{CC} = 5 V, R_L = 1 k\Omega$			0.5	μs
Storage time	tstg	$V_{I} = 5 V, PW = 2 \mu s$			3.0	μs
Turn-off time	t _{off}	duty cycle≤2 %			5.0	μs

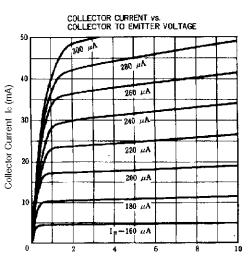
** Pulse test PW \leq 350 μ s, duty cycle \leq 2 %

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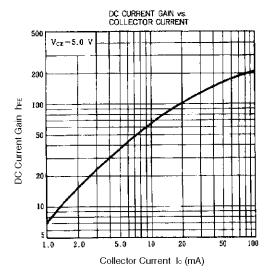
TYPICAL CHARACTERISTICS (Ta = 25°C)

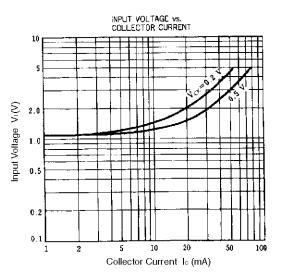


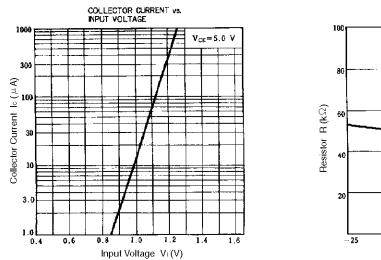


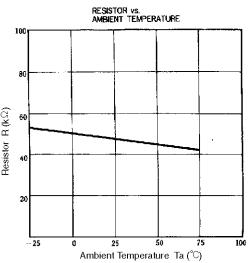


Collector to Emitter Voltage V $_{\text{CE}}$ (V)









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